TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP131

Programmable Controllers AC / DC-Input Module Telecommunication

The TOSHIBA mini flat coupler TLP131 is a small outline coupler, suitable for surface mount assembly.

TLP131 consists of a photo transistor, optically coupled to a gallium arsenide infrared emitting diode.

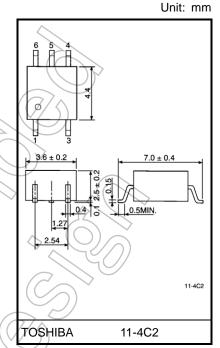
- Collector-emitter voltage: 80 V (min)
- Current transfer ratio: 50% (min)

Rank GB: 100% (min)

- Isolation voltage: 3750 Vrms (min)
- UL recognized: UL1577, file No. E67349
- c-UL approved :CSA Component Acceptance Service

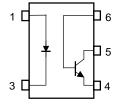
No. 5A, File No.E67349

TLP131 base terminal is for the improvement of speed, reduction of dark current, and enable operation. Using by base terminal opening is easy to receive the outside noise.



Weight: 0.09 g (typ.)

Pin Configurations (top view)



- 1 : Anode
- 3 : Cathode
- 4 : Emitter
- 5 : Collector
- 6 : Base

Current Transfer Ratio

	Current Transfer Ratio (%) (Ic/IF)		
Classification	I _F = 5 mA, V _{CE} = 5 V, Ta = 25°C		Marking Of Classification
	Min	Max	
Blank	50	600	Blank, Y, Y [■] , YE, G, G [■] , GR, B, B [■] , BL, GB
Rank Y	50	150	YE
Rank GR	100	300	GR
Rank BL	200	600	BL (V)
Rank GB	100	600	GB
Rank YH	75	150	Y= () >
Rank GRL	100	200	G
Rank GRH	150	300	
Rank BLL	200	400	В

Note: Please ask your local retailer about the devices with Rank Y or Rank BL.

Note: Application type name for certiffication test, please use standard product type name, i.e. TLP131(GB): TLP131



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TLP131



Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	IF	50	mA
	Forward current derating (Ta ≥ 53°	C) ΔI _F /°C	-0.7	mA/°C
	Peak forward current (100 µs pulse, 100 p	s) IFP	1 <	Α
LED	Reverse voltage	VR	5	V
	Diode power dissipation	PD	100	mW
	Diode power dissipation derating (Ta ≥ 53°	C) ΔPD/°C	-1.39	mW/°C
	Junction temperature	Tj	125	°C °C
	Collector-emitter voltage	VCEO	80	// v
	Collector-base voltage	V _{CBO}	80	V
	Emitter-collector voltage	VECO	7	V
jo	Emitter-base voltage	VEBO		X ()
Detector	Collector current	Ic	50	mA
۵	Peak collector current (10 ms pulse, 100 p	os) ICP	100	mA >
	Power dissipation	Pc	150	mW
	Power dissipation derationg (Ta ≥ 25	C) ΔPc/°C	-1.5	mW/°C
	Junction temperature	(Tj	125	°C
Stor	rage temperature range	Tstg	-55 to 125	√ °c
Оре	erating temperature range	Topr	-55 to 100	°C
Lea	d soldering temperature (1	(s) T _{sol}	260	°C
Tota	al package power dissipation	PT	200	mW
Tota	al package power dissipation derating (Ta ≥ 25°	C) ΔPT/°C	-2.0	mW/°C
Isola	ation voltage (AC, 60 s, RH ≤ 60%) (Note	1) BVs	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: Pins 1 and 3 shorted together, and pins 4, 5 and 6 shorted together.

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Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	48	V
Forward current	lF	_	16	25	mA
Collector current	IC	_	1	10	mA
Operating temperature	Topr	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	IF = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	IR	V _R = 5 V	_((10	μΑ
	Capacitance	Ст	V = 0 V, f = 1 MHz		30	/ _	pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5 mA	80)	ı	٧
	Emitter-collector breakdown voltage	V _{(BR)ECO}	le = 0;1 mA	7	-	1	V
	Collector-base breakdown voltage	V(BR)CBO	I _C = 0.1 mA	80	_	_	V
	Emitter-base breakdown voltage	V(BR)EBO	IE = 0.1 mA	7			٧
Detector	collector dark current	ICEO	V _{CE} = 48 V	1	10	100	nA
Det	collector dark current	ICEU	V _{CE} = 48 V, Ta = 85°C	-	2	50	μΑ
	Collector dark current	ICER	V _{CE} = 48 V, Ta = 85°C R _{BE} = 1 MΩ	ı	0.5	10	μΑ
	Collector dark current	I _{CBO}	V _{CB} = 10 V	1	0.1	_	nA
	DC forward current gain	hFE	$V_{CE} = 5 \text{ V, IC} = 0.5 \text{ mA}$	_	400	_	_
	Capacitance (collector to emitter)	CCE	V = 0 V, f = 1 MHz	_	10	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	1-11-	IF = 5 mA, VCE = 5 V	50	_	600	%
Current transfer fatto	IC/IF	Rank Gl	100	_	600	70
Saturated CTR		IF = 1 mA, VCE = 0.4 V	_	60	_	%
Saturated CTR	IC/IF(sat)	Rank Gl	30		_	70
Base photo-current	IPB	I _F = 5 mA, V _{CB} = 5 V	_	10	_	μΑ
		I _C = 2.4 mA, I _F = 8 mA	_	_	0.4	
Collector-emitter saturation voltage	VCE(sat)	I _C = 0.2 mA, I _F = 1 mA	_	0.2	_	V
		Rank Gl	3 –	_	0.4	
Off-state collector current	IC(off)	IF = 0.7 mA, VCE = 48 V	_	1	10	μΑ

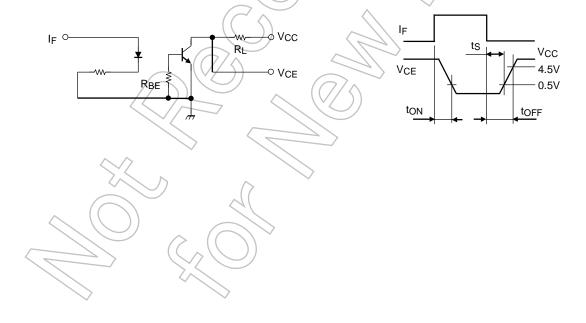
Isolation Characteristics (Ta = 25°C)

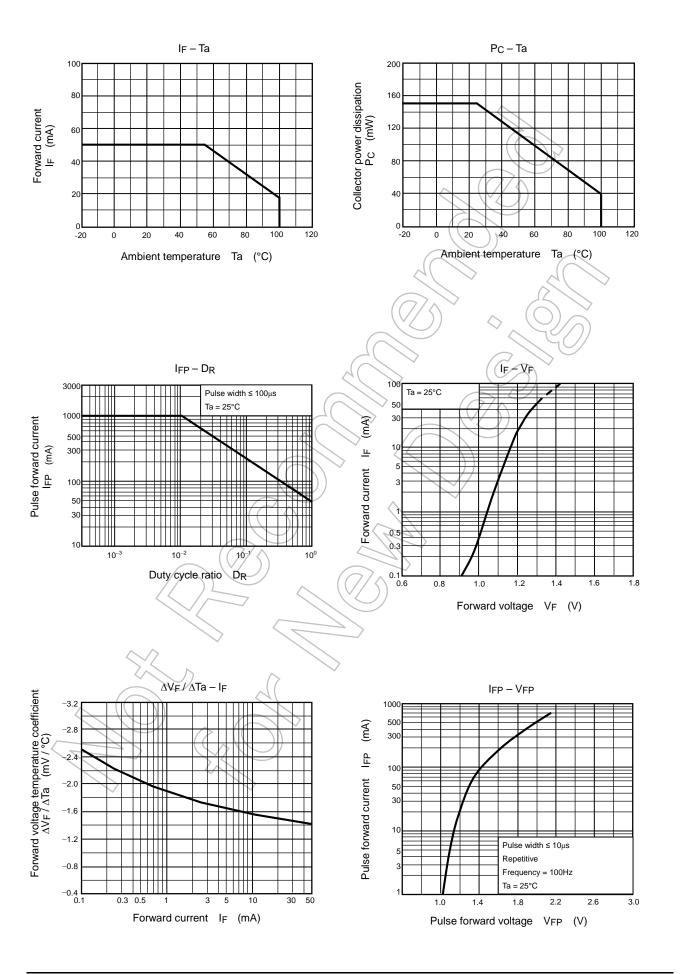
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	Vs = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	Vs = 500 V, RH ≤ 60%	5×10 ¹⁰	10 ¹⁴	_	Ω
		AC, 60 s	3750	_	_	Vrms
Isolation voltage	BVs	AC, 1 s, in oil		10000	_	VIIIIS
		DC, 60 s, in oil	1	10000	_	Vdc

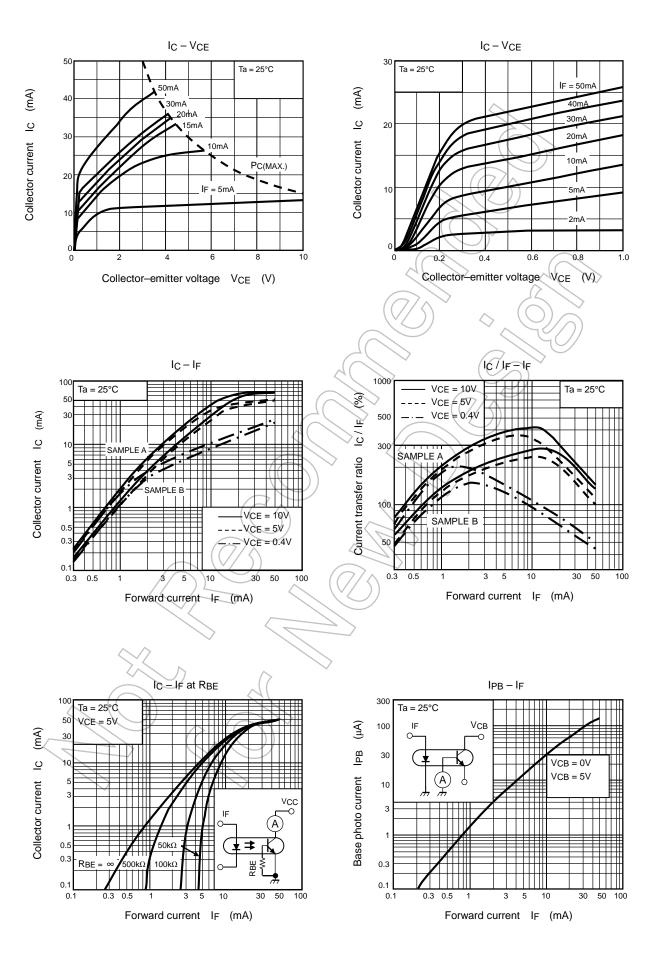
Switching Characteristics (Ta = 25°C)

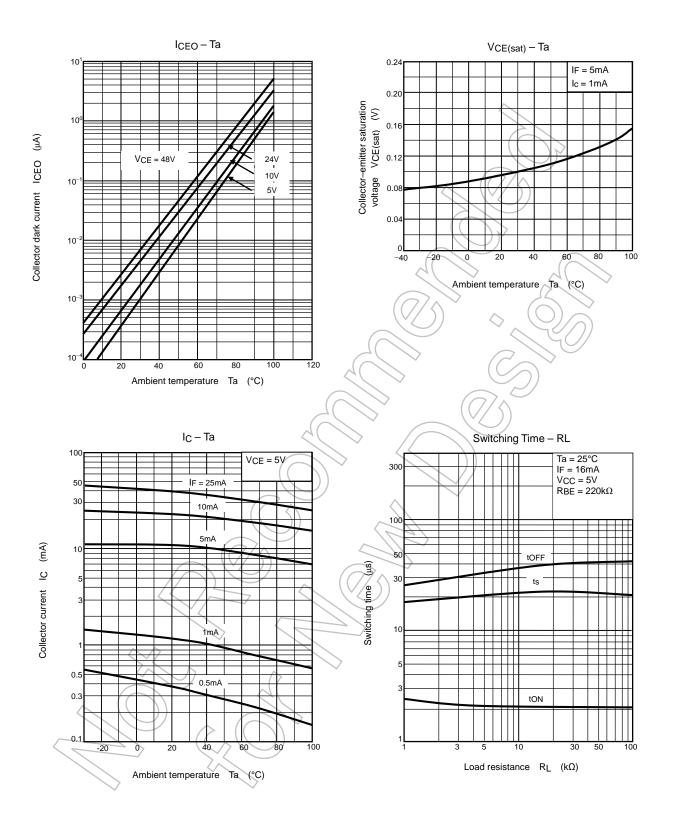
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Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	t _r		_	2	_	
Fall time	tf	VCC = 10 V, IC = 2 mA		3	\rightarrow	
Turn-on time	ton	R _L = 100 Ω	-6	3	> —	μS
Turn-off time	t _{off}		~_(3) —	
Turn-on time	ton	$R_L = 1.9 \text{ k}\Omega$ (Fig.1)		2	_	
Storage time	ts	RBE = OPEN		25	_	μS
Turn-off time	toff	VCC = 5 V, IF = 16 mA		40	_	
Turn-on time	ton	$R_L = 1.9 \text{ k}\Omega$ (Fig.1)	\ -	2	_	
Storage time	t _s	$R_{BE} = 220 \text{ k}\Omega$	/ _	20	_	μS
Turn-off time	toff	Vcc = 5 V, I _F = 16 mA		30		

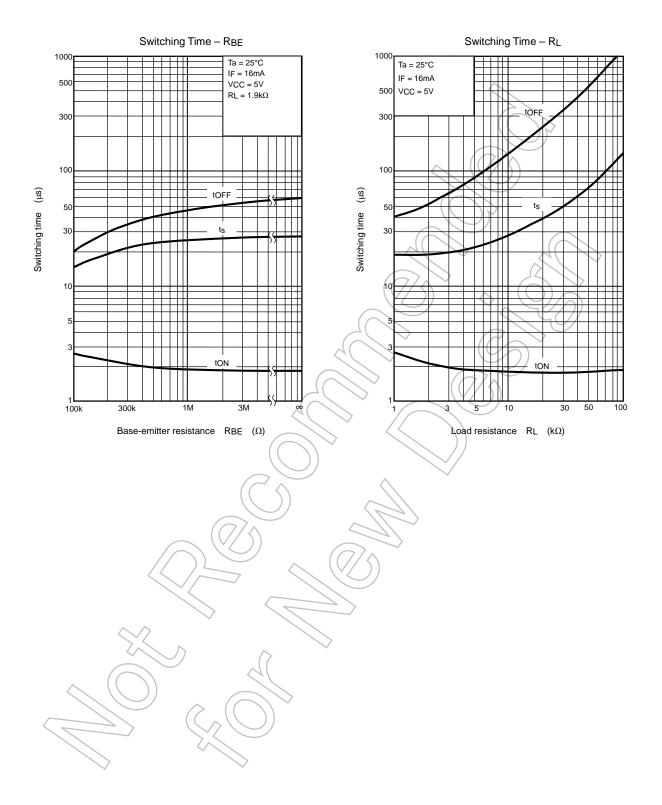
Fig. 1 Switching time test circuit











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